

# UMS-1800-A16-G

#### OCTAVE BAND VOLTAGE CONTROLLED OSCILLATOR

Package: A16, 12.7mm x 12.7mm x 3.43mm

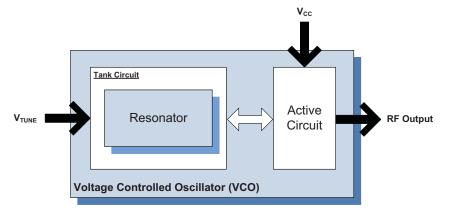


### Features

- Octave Band Tuning
- Frequency: 900MHz to 1800MHz
- Resonator: Microstrip
- PCB: Rogers
- Package Size: 12.7mm x 12.7mm x 3.43mm (0.5in x 0.5in x 0.135in)

## Applications

- Wide Band Applications
- Built-in Test Applications
- First LO Applications
- Frequency Sythesizers



Functional Block Diagram

## **Product Description**

This series of VCO modules features full octave bands (typical), low phase noise, low harmonics, and linear tuning.

#### **Ordering Information**

UMS-1800-A16-G Contact us at 1-480-756-6070

#### **Optimum Technology Matching® Applied**

🗌 GaAs HBT	SiGe BiCMOS	🗌 GaAs pHEMT
GaAs MESFET	Si BiCMOS	□ Si CMOS
🗌 InGaP HBT	SiGe HBT	🗹 Si BJT

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GaN HEMT BIFET HBT

## UMS-1800-A16-G



#### **Absolute Maximum Ratings**

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Parameter	Rating	Unit
Operating Ambient Temperature[1]	-40 to +85	°C
Storage Temperature	-55 to +125	°C

[1] Frequency drift: 13.0MHz typical (either extreme)



#### **Caution!** ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2002/95/EC.

Parameter		Specification		11	
	Min.	Тур.	Max.	Unit	Condition
Overall					
Frequency Range	900		1800	MHz	
Tuning Voltage	0.5		15	V <sub>DC</sub>	
Tuning Sensitivity		80		MHz/V	
Output Power	10	12.5	15	dBm	
	10			dBm	At V <sub>T</sub> =0
Output Phase Noise		-75	-70	dBc/Hz	1kHz
		-100	-95	dBc/Hz	10kHz
		-120	-115	dBc/Hz	100kHz
		-140	-135	dBc/Hz	1000kHz
Second Harmonic		-20	-15	dBc	
Frequency Pulling		8	15	MHz p-p	At 12dBr, all phases
Tuning Port Capacitance		100		pF	
Modulation Bandwidth		15000		kHz	3dB BW
Frequency Pushing		0.5	1	MHz/V	
Power Supply	· · ·				
Operating Voltage		12		V	
Supply Current		32		mA	





## **Package Drawing & Pin Outs**

12.7mm x 12.7mm x 3.43mm (0.5in x 0.5in x 0.135in)

